

P15LF6QTKD

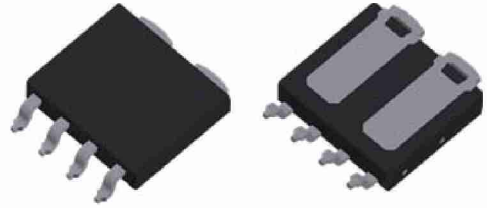
Power MOSFETs
60V, 15A, Dual N-channel

Feature

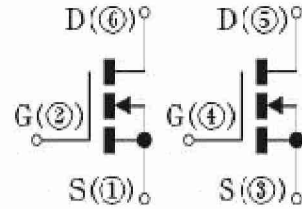
- N-channel
- Small SMD
- Dual type
- 4.5V Gate Drive
- Low Capacitance
- Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): LF_Dual



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C, per FET)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T _{stg}		-55 to 175	°C
Channel temperature	T _{ch}		-55 to 175	°C
Drain-source voltage	V _{DSS}		60	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		15	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, duty=1/100	45	A
Continuous source current(DC)	I _S		15	A
Total power dissipation	P _T	With heatsink	35	W
Total power dissipation	P _T	※	2.5	W
Total power dissipation	P _T	※	1.5	W
Single avalanche current	I _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	11	A
Single avalanche energy	E _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	13	mJ

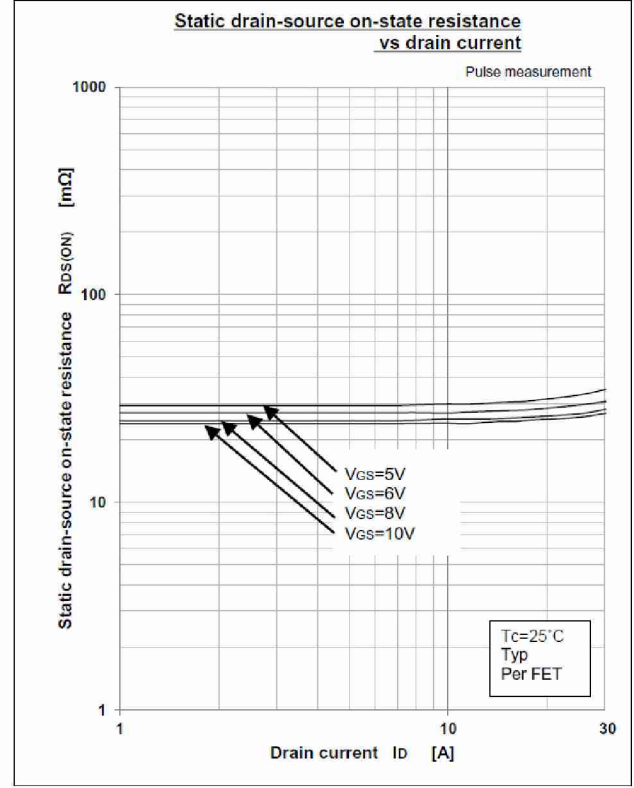
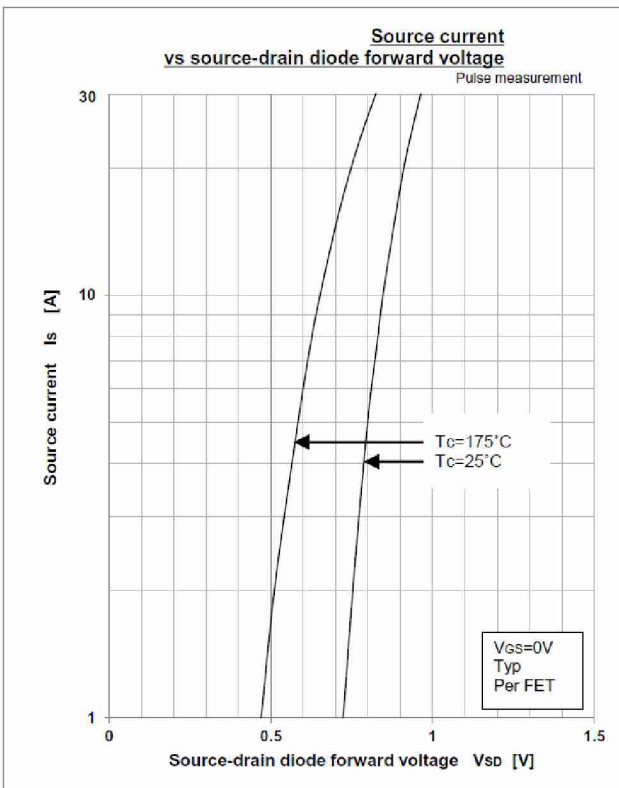
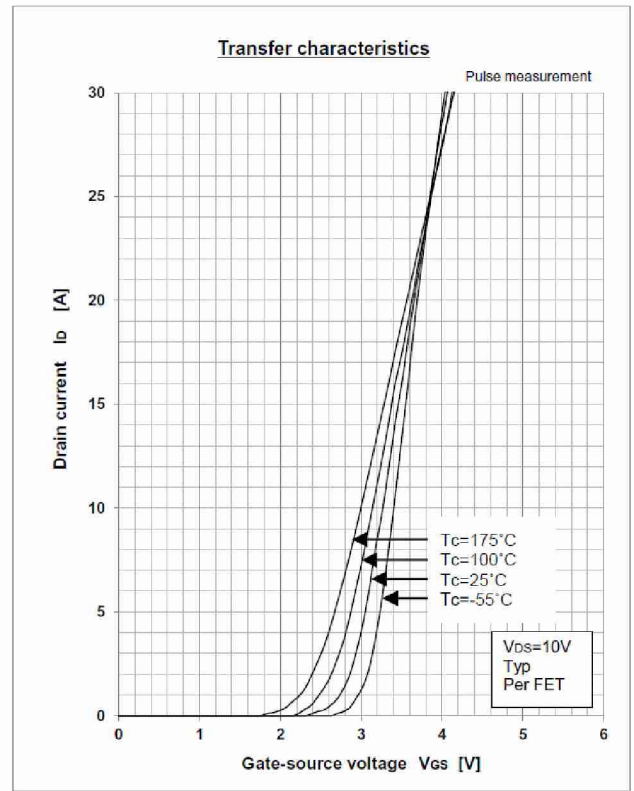
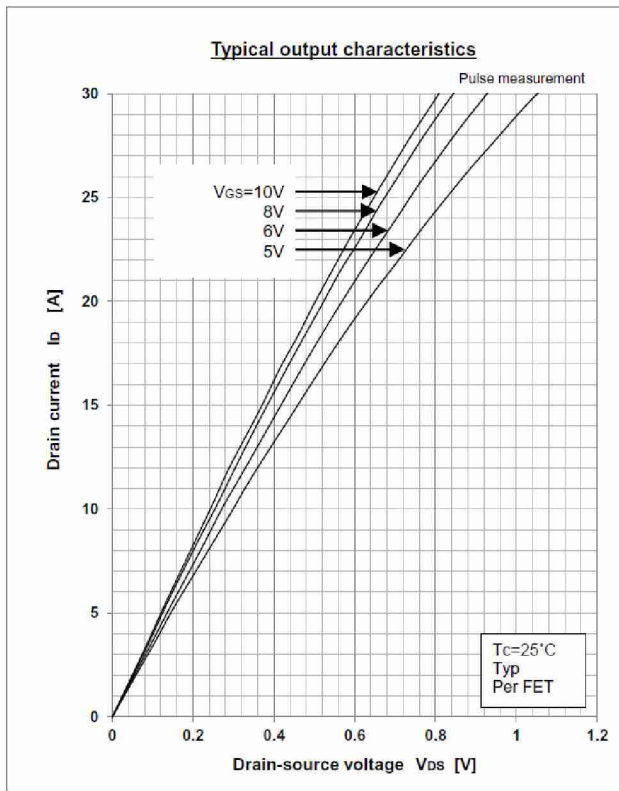
※ :See the original Specifications

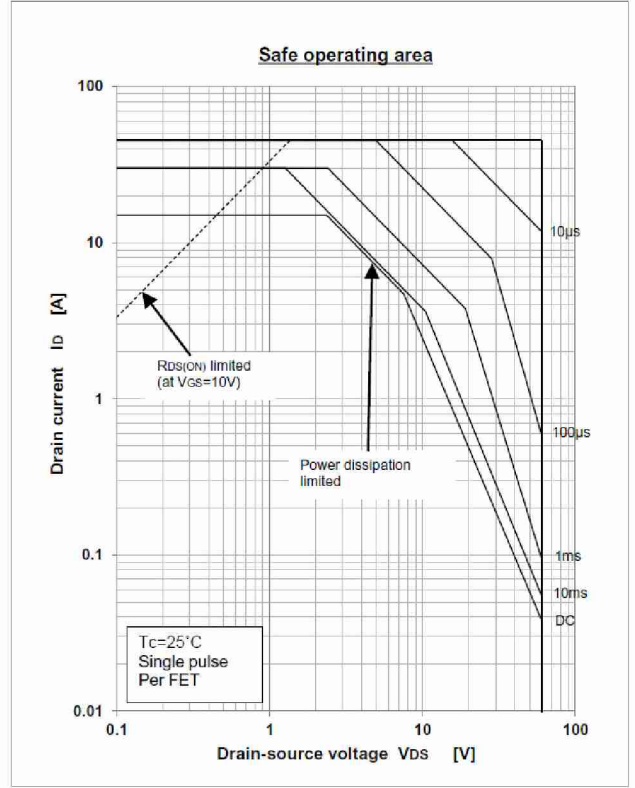
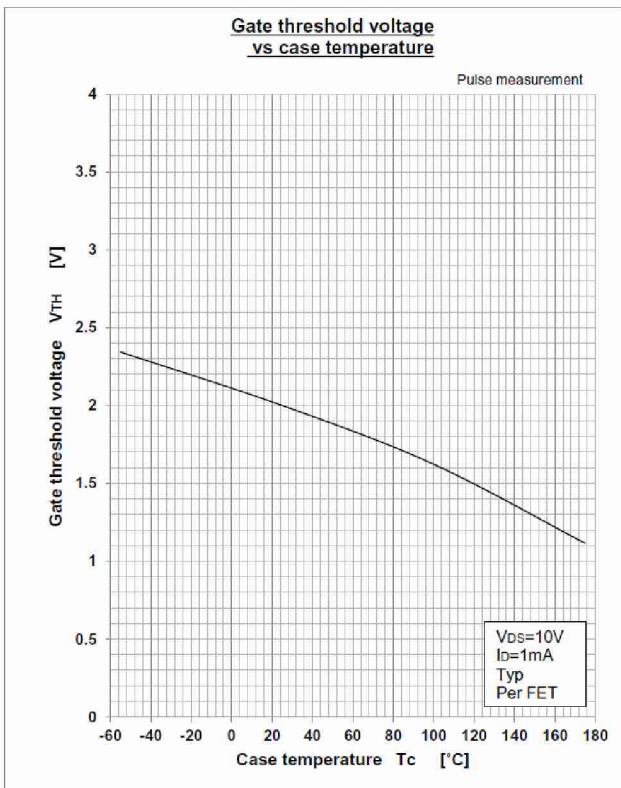
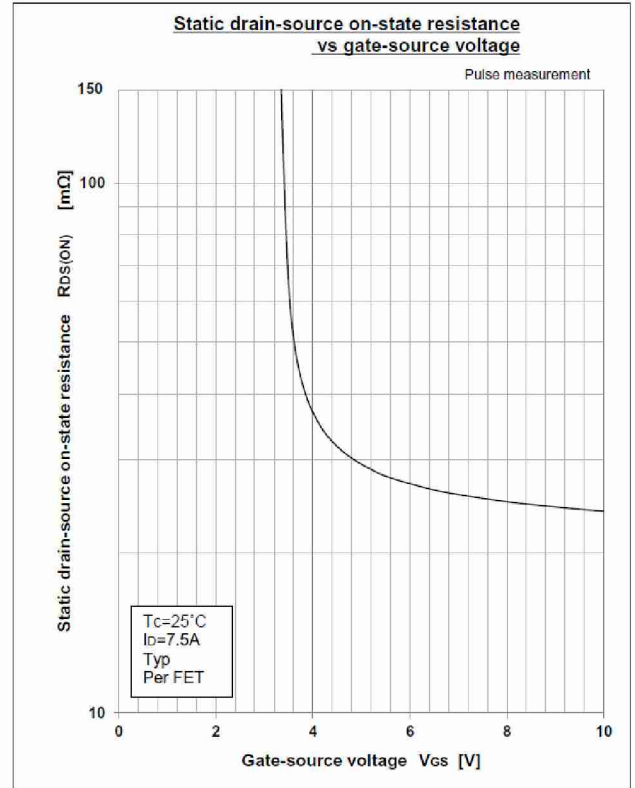
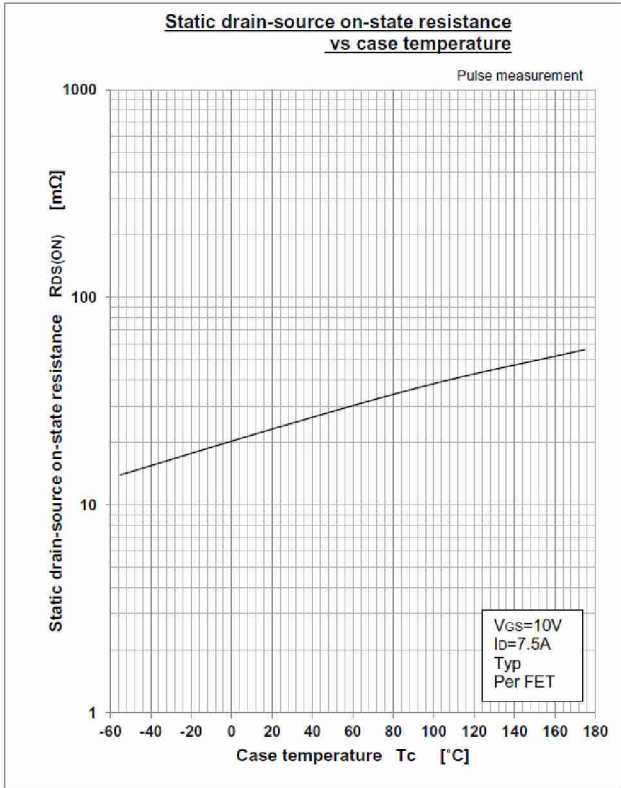
Electrical Characteristics (unless otherwise specified : Tc=25°C, per FET)

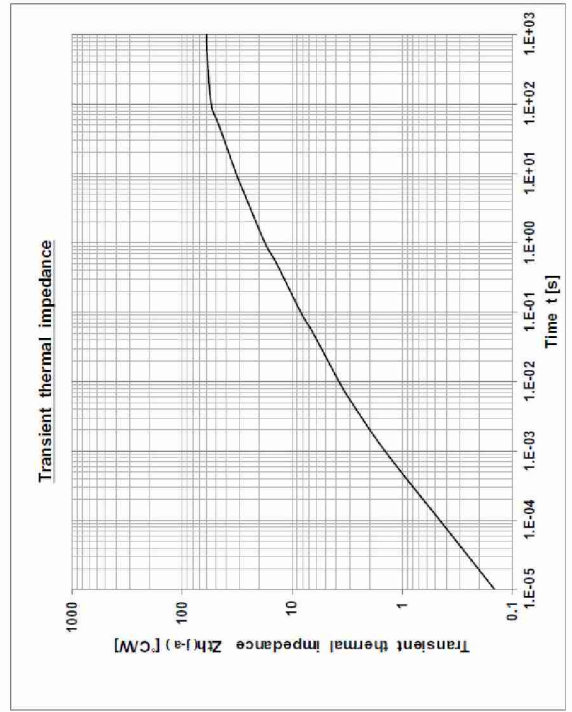
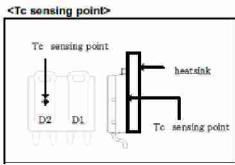
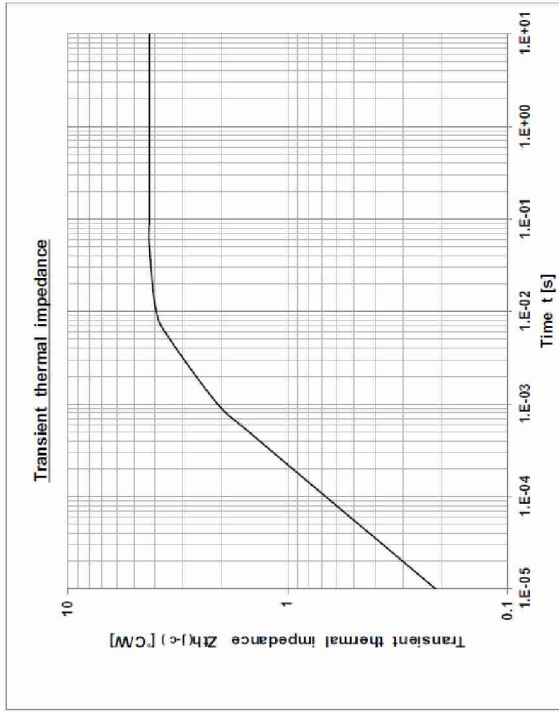
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	60			V
Zero gate voltage drain current	I_{DSS}	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=7.5A, VDS=10V	4			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=7.5A, VGS=10V		0.024	0.03	Ω
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=7.5A, VGS=4.5V		0.032	0.043	Ω
Gate threshold voltage	V_{th}	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	V_{SD}	IS=15A, VGS=0V			1.2	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink			4.25	°C/W
Thermal resistance	$R_{th(j-a)}$	Junction to ambient ※			60	°C/W
Thermal resistance	$R_{th(j-a)}$	Junction to ambient ※			100	°C/W
Total gate charge	Q_g	VDD=48V, VGS=10V, ID=15A		15		nC
Gate to source charge	Q_{gs}	VDD=48V, VGS=10V, ID=15A		4.1		nC
Gate to drain charge	Q_{gd}	VDD=48V, VGS=10V, ID=15A		3.9		nC
Input capacitance	C_{iss}	VDS=25V, VGS=0V, f=1MHz		632		pF
Reverse transfer capacitance	C_{rss}	VDS=25V, VGS=0V, f=1MHz		38		pF
Output capacitance	C_{oss}	VDS=25V, VGS=0V, f=1MHz		86		pF
Turn-on delay time	$t_{d(on)}$	ID=7.5A, RL=4.00Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		3.5		ns
Rise time	t_r	ID=7.5A, RL=4.00Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		9.5		ns
Turn-off delay time	$t_{d(off)}$	ID=7.5A, RL=4.00Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		12		ns
Fall time	t_f	ID=7.5A, RL=4.00Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4		ns
Diode reverse recovery time	t_{rr}	IF=15A, VGS=0V, di/dt=100A/μs		35		ns
Diode reverse recovery charge	Q_{rr}	IF=15A, VGS=0V, di/dt=100A/μs		32		nC

※ :See the original Specifications

CHARACTERISTIC DIAGRAMS

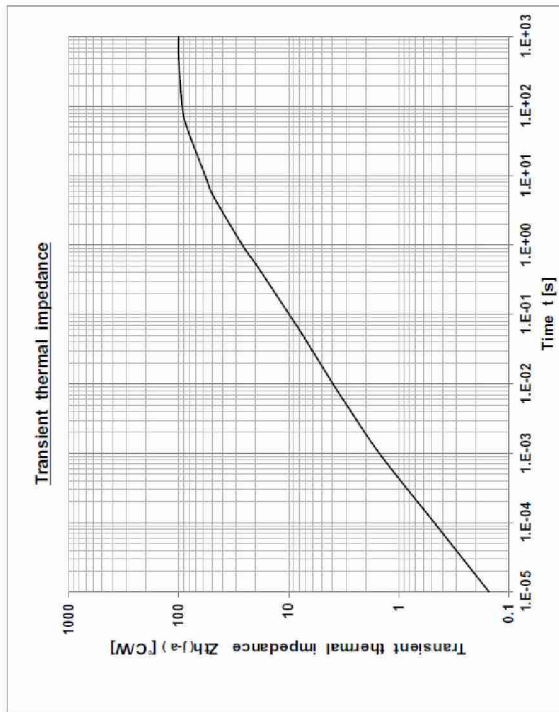






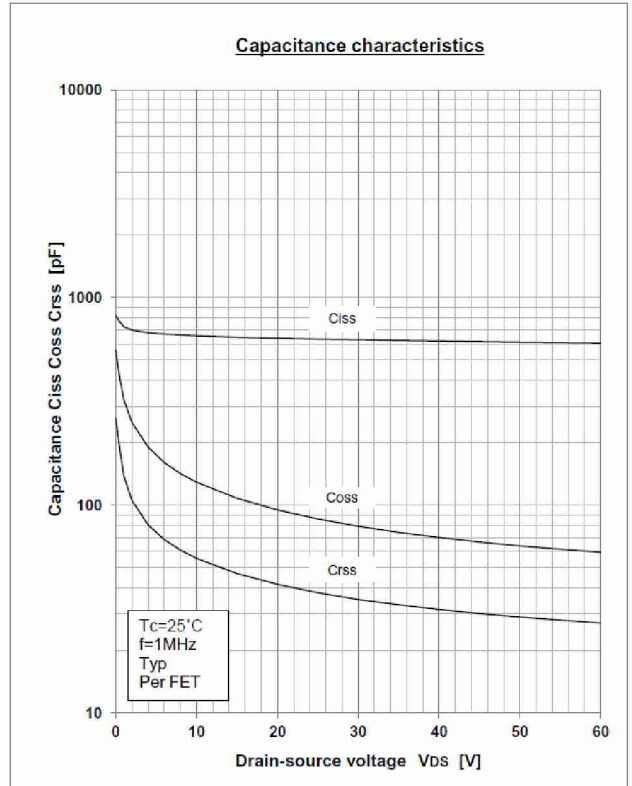
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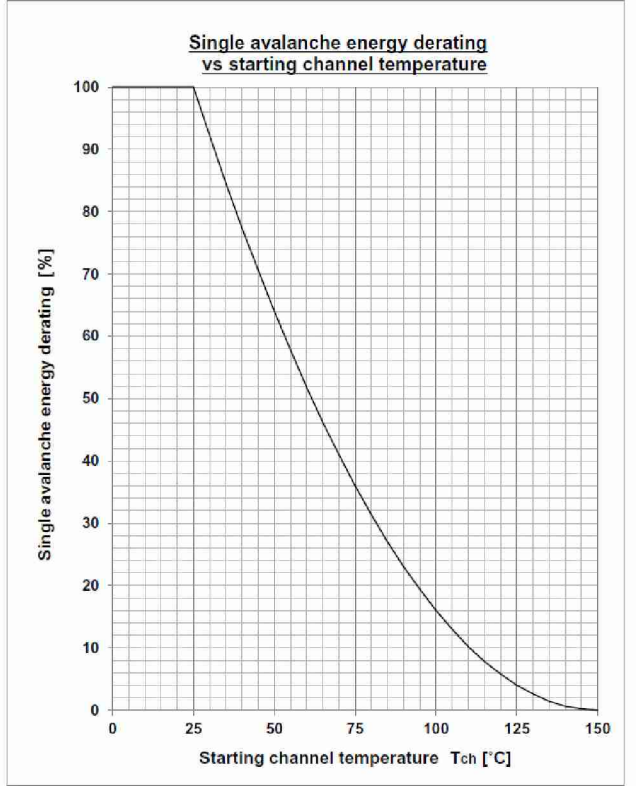
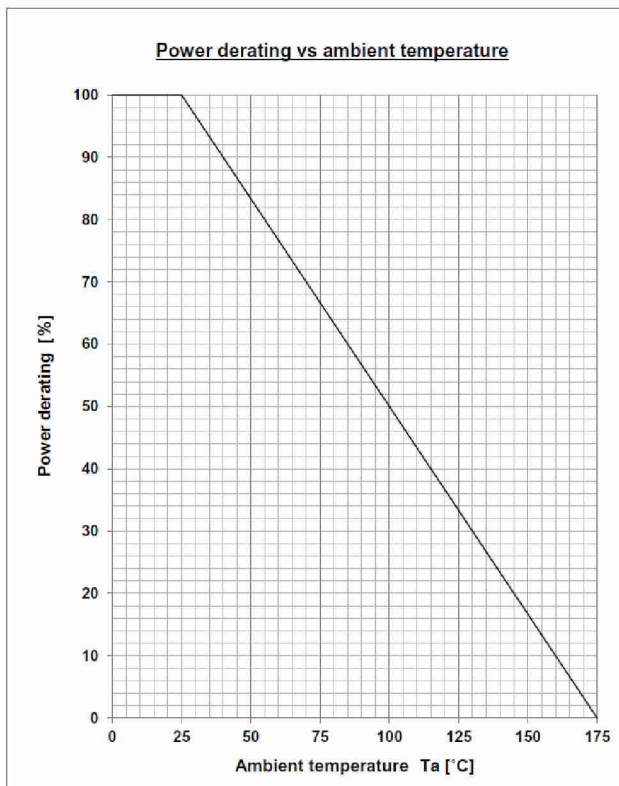
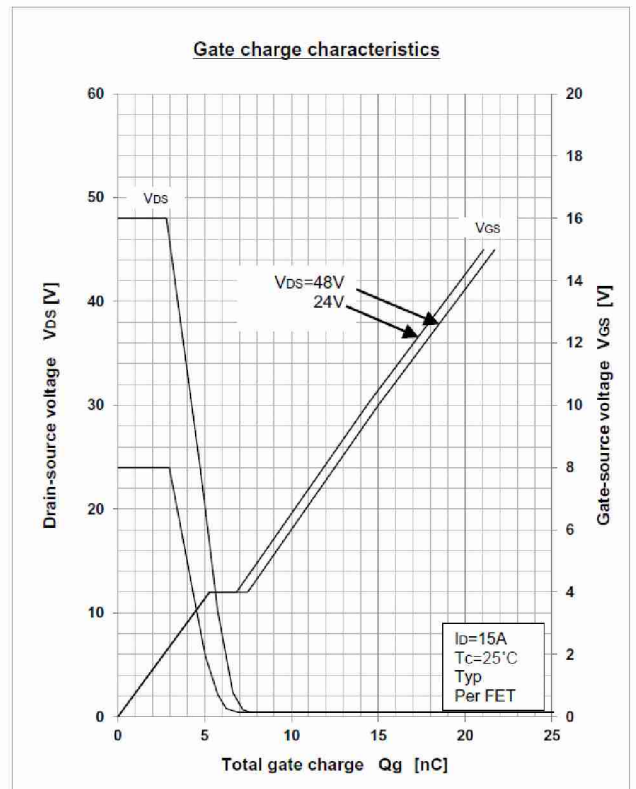
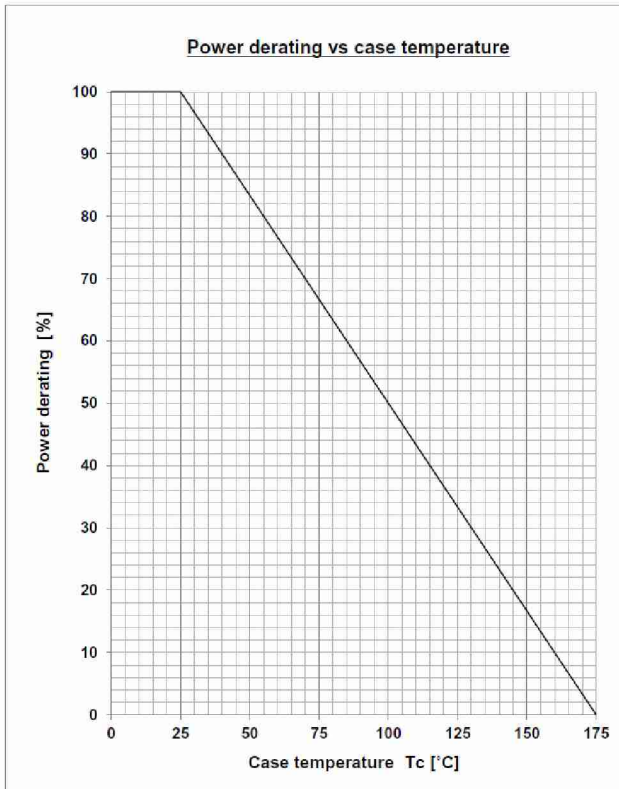
Type	Glass-epoxy
Size	1 inch ²
Thickness	1.6 mm
Conductor thickness	70 μm
Pattern area	629.42 mm ²



<Substrate detail>

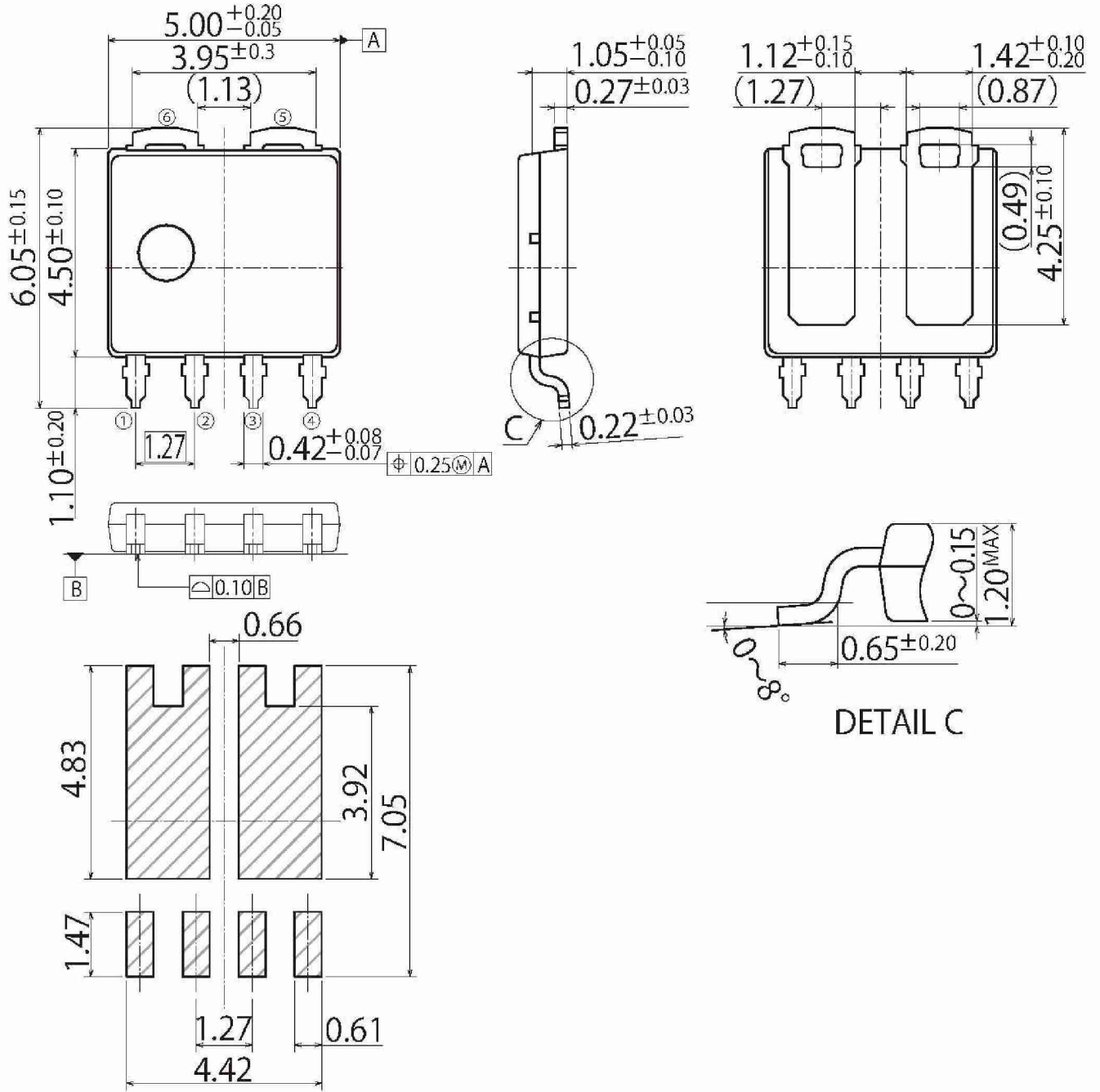
Type	Glass-epoxy
Size	1 inch ²
Thickness	1.6 mm
Conductor thickness	70 μm
Pattern area	91.34 mm ²





G8

JEDEC Code	-
JEITA Code	-
House Name	LF_Dual



Referential Soldering Pad

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